

1-Line Ultra Small Bi-directional TVS Diode

Description

The PESDU3311P0 is a bi-directional TVS diode. to provide fast-response time and low ESD clamping voltage, making this device an ideal solution for protecting voltage sensitive data. The PESDU3311P0 complies with the IEC 61000-4-2 (ESD) standard with ±30kV air and ±30kV contact discharge. It is assembled into an ultra-small 0.6x0.3x0.3mm lead-free DFN package. The ultra-small size and high ESD protection make PESDU3311P0 an ideal choice to replace 0201 size multilayer varistors (MLVs) and protect cell phone, digital cameras, audio players and many other portable applications.

Features

Ultra small package: 0.6x0.3x0.3mm

Protects one data or power line

Operating voltage: 3.3V

Low clamping voltage

2-pin leadless package

Complies with following standards:

- IEC 61000-4-2 (ESD) immunity test

Air discharge: ±30kV Contact discharge: ±30kV

- IEC61000-4-5 (Lightning) 8A (8/20µs)

RoHS Compliant

- Package: DFN0603-2 (0.6×0.3×0.3mm) Case Material: "Green" Molding Compound.
- Moisture Sensitivity: Level 1 per J-STD-020
- Marking Information: See Below

Mechanical Characteristics

Applications

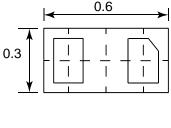
- Cellular Handsets and Accessories
- Personal Digital Assistants
- Notebooks and Handhelds
- Portable Instrumentation
- **Digital Cameras**
- Peripherals
- **Audio Players**
- Keypads, Side Keys, LCD Displays

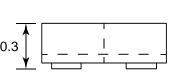
Marking Information

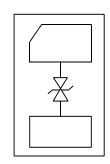


A3= Device Marking Code

Dimensions and Pin Configuration







Package Dimensions

Circuit and Pin Schematic

Ordering Information

| Part Number | Shipping | Reel Size |
|-------------|-------------------|--------------|
| PESDU3311P0 | 10000/Tape & Reel | 7 inch |



Absolute Maximum Ratings (TA=25°C unless otherwise specified)

| Parameter | Symbol | Value | Unit | |
|---------------------------------|------------------|--------------------|------|--|
| Peak Pulse Power (8/20µs) | РРК | 80 | W | |
| Peak Pulse Current (8/20µs) | Ірр | 8 | А | |
| ESD per IEC 61000-4-2 (Air) | V | ±30 | 137 | |
| ESD per IEC 61000-4-2 (Contact) | V _{ESD} | ±30 | kV | |
| Lead temperature | T∟ | 260 | C | |
| Operating Temperature Range | Тор | -40 ~ +85 | C | |
| Storage Temperature Range | Тѕтс | −55 ~ + 150 | °C | |

Electrical Characteristics (TA=25°C unless otherwise specified)

| Parameter | Symbol | Min | Тур | Max | Unit | Test Condition |
|----------------------------------|------------------|-----|------|-----|------|----------------------------------|
| Reverse Working Voltage | V _{RWM} | | | 3.3 | ٧ | |
| Breakdown Voltage | V _{BR} | 3.8 | | | V | I⊤ = 1mA |
| Reverse Leakage Current | I _R | | | 1 | μA | V _{RWM} =3.3V |
| Clamping voltage 1) | V _{CL} | | 8 | | V | IPP=16A, tp=100ns |
| Dynamic resistance ¹⁾ | R _{DYN} | | 0.25 | | Ω | |
| Clamping Voltage ²⁾ | Vc | | 8 | | V | V _{ESD} = 8kV |
| Clamping Voltage ³⁾ | Vc | | 5.5 | 7 | V | I _{PP} = 1A, tp =8/20μs |
| Clamping Voltage ³⁾ | Vc | | 8 | 10 | V | I _{PP} =8A, tp =8/20µs |
| Junction Capacitance | CJ | | 13 | 20 | pF | V _R = 0V, f = 1MHz |

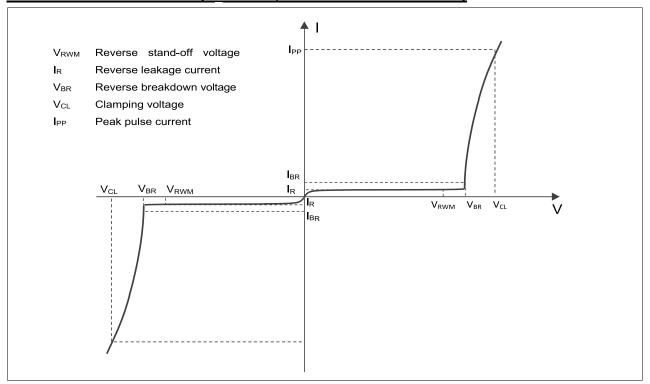
Notes:

- 1) TLP parameter: $Z_0 = 50\Omega$, tp = 100ns, tr = 2ns, averaging window from 60ns to 80ns. RDYN is calculated from 4A to 16A.
- 2) Contact discharge mode, according to IEC61000-4-2.
- 3) Non-repetitive current pulse, according to IEC61000-4-5.

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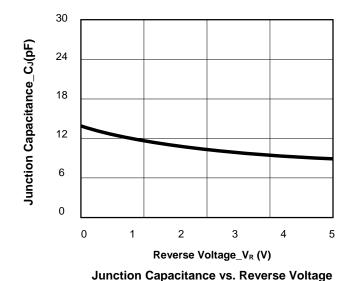
Electrical characteristics (T_A = 25℃, unless otherwise noted)

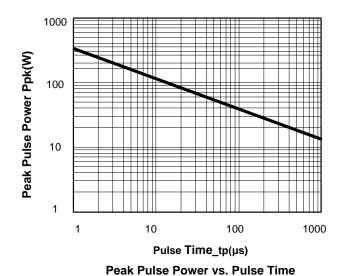


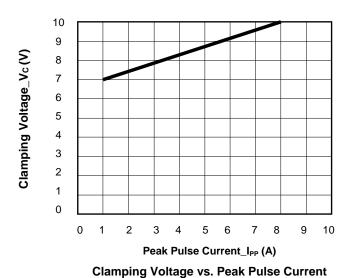
Definitions of electrical characteristics

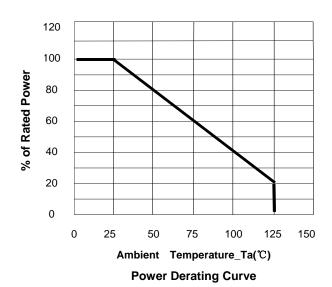


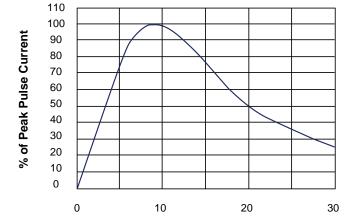
Typical Performance Characteristics (TA=25°C unless otherwise Specified)

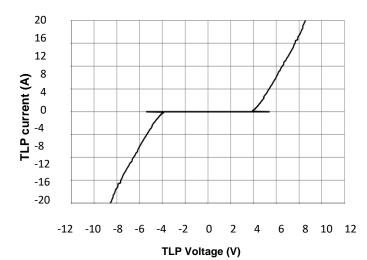










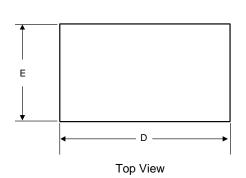


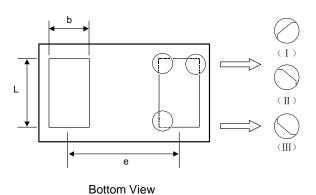
Time_t(μs) 8/20μs Pulse Waveform

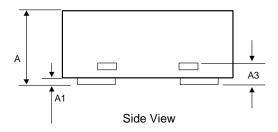
TLP Measurement



DFN0603-2 Package Outline Drawing

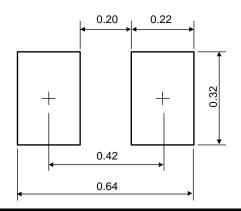






| | D | Dimensions in Millimeters | | | |
|--------|-------|---------------------------|-------|--|--|
| Symbol | Min. | Тур. | Max. | | |
| А | 0.230 | 0.300 | 0.350 | | |
| A1 | 0.000 | - | 0.050 | | |
| А3 | | 0.102REF. | | | |
| D | 0.550 | 0.600 | 0.670 | | |
| Е | 0.250 | 0.300 | 0.370 | | |
| b | 0.160 | 0.190 | 0.230 | | |
| L | 0.215 | 0.245 | 0.275 | | |
| е | | 0.360 BSC | | | |

Recommended PCB Layout (Unit: mm)

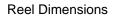


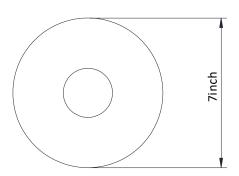
Notes:

This recommended land pattern is for reference purposes only. Please consult your manufacturing group to ensure your PCB design guidelines are met.

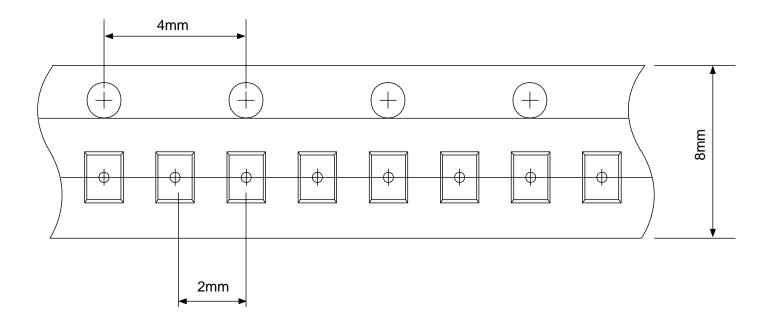


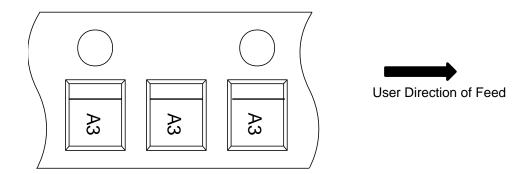
TAPE AND REEL INFORMATION





Tape Dimensions







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